

PLT09-151S



150W 100÷500MHz Amplifier



GENERAL INFORMATION

The 150W Carrier Power Amplifier it is a Class AB, Low Distortion, High Gain Linear amplifier module for the 100 ÷ 500MHz band.

Superior performances are obtained using broadband matching techniques and the finest Gold LDMOS transistors available on the market today.

Matched for 50 Ohms input and output, with Shutdown, Current Monitoring, and Temperature alarm the Broadband Amplifier it is suitable for AM communication application.

TECHNICAL SPECIFICATIONS (th = 25 °C; 50 Ω loaded; VDS = +48Vdc)

Frequency Range: 100÷500MHz

Output Power: >150W CW into 3:1 VSWR, all phase angles. Power Gain: 10/13/17dB (measured at Pout 100W)

Efficiency: >30% (at Pout =150W)

Supply Voltage: +48Vdc Working Class: AB Bias Current: 2x1.5A 2 tone IMD @ 100W: 25dBc min Even order harmonics @ 150W: >30dBc -25dBc Odd order harmonics @ 150W: Input return loss: <10dB Gain flatness @ 150W: <±1dB Spurious signals: <70dBc

(non harmonic related) @ 150W

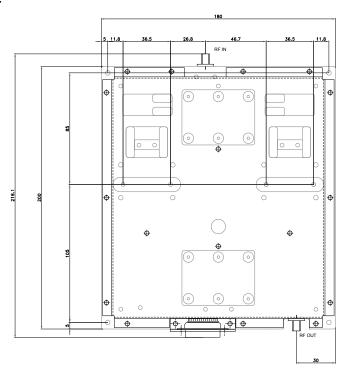
Operating Base plate temp: 75deg/C (90deg/C of flange) high temperature

-20deg/C baseplate low temperature

Dimensions: 180x216x33,5mm

Weight: 1 kg

RF MODULE LAYOUT



AM AMPLIFIER